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Embedded - System On Chip (SoC): The Heart of Modern Embedded Systems

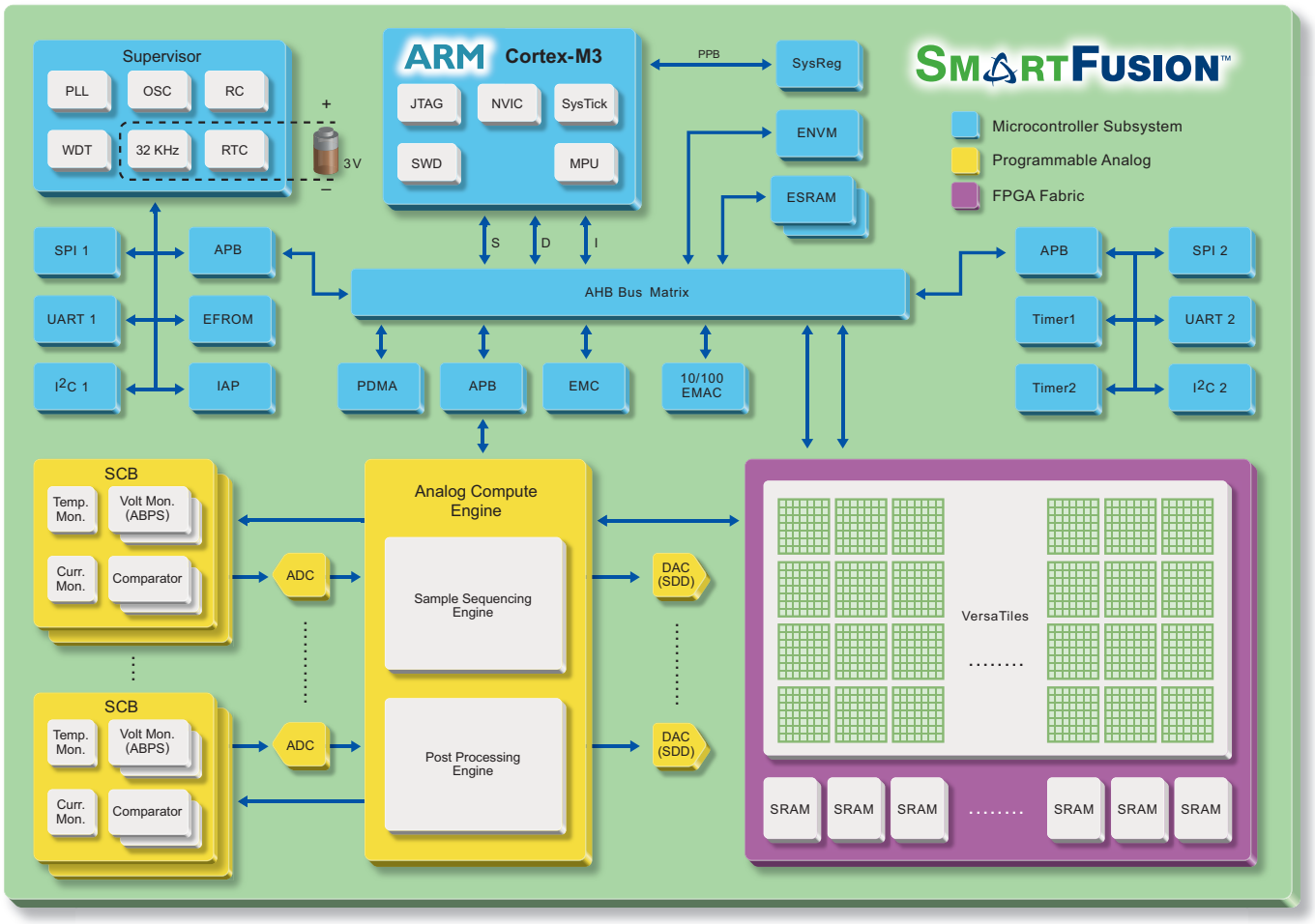
Embedded - System On Chip (SoC) refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

What are Embedded - System On Chip (SoC)?

System On Chip (SoC) integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

Details	
Product Status	Obsolete
Architecture	MCU, FPGA
Core Processor	ARM® Cortex®-M3
Flash Size	128KB
RAM Size	16KB
Peripherals	DMA, POR, WDT
Connectivity	EBI/EMI, I²C, SPI, UART/USART
Speed	100MHz
Primary Attributes	ProASIC®3 FPGA, 60K Gates, 1536D-Flip-Flops
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	288-TFBGA, CSPBGA
Supplier Device Package	288-CSP (11x11)
Purchase URL	https://www.e-xfl.com/product-detail/microsemi/a2f060m3e-1cs288

SmartFusion cSoC Block Diagram



Legend:

SDD – Sigma-delta DAC
SCB – Signal conditioning block
PDMA – Peripheral DMA
IAP – In-application programming
ABPS – Active bipolar prescaler
WDT – Watchdog Timer
SWD – Serial Wire Debug

Power Consumption of Various Internal Resources

***Table 2-14* • Different Components Contributing to Dynamic Power Consumption in SmartFusion cSoCs**

Parameter	Definition	Power Supply		Device			Units
		Name	Domain	A2F060	A2F200	A2F500	
PAC1	Clock contribution of a Global Rib	VCC	1.5 V	3.39	3.40	5.05	µW/MHz
PAC2	Clock contribution of a Global Spine	VCC	1.5 V	1.14	1.83	2.50	µW/MHz
PAC3	Clock contribution of a VersaTile row	VCC	1.5 V	1.15	1.15	1.15	µW/MHz
PAC4	Clock contribution of a VersaTile used as a sequential module	VCC	1.5 V	0.12	0.12	0.12	µW/MHz
PAC5	First contribution of a VersaTile used as a sequential module	VCC	1.5 V	0.07	0.07	0.07	µW/MHz
PAC6	Second contribution of a VersaTile used as a sequential module	VCC	1.5 V	0.29	0.29	0.29	µW/MHz
PAC7	Contribution of a VersaTile used as a combinatorial module	VCC	1.5 V	0.29	0.29	0.29	µW/MHz
PAC8	Average contribution of a routing net	VCC	1.5 V	1.04	0.79	0.79	µW/MHz
PAC9	Contribution of an I/O input pin (standard dependent)	VCCxxxxIOBx/VCC	See Table 2-10 and Table 2-11 on page 2-11				
PAC10	Contribution of an I/O output pin (standard dependent)	VCCxxxxIOBx/VCC	See Table 2-12 and Table 2-13 on page 2-11				
PAC11	Average contribution of a RAM block during a read operation	VCC	1.5 V	25.00			µW/MHz
PAC12	Average contribution of a RAM block during a write operation	VCC	1.5 V	30.00			µW/MHz
PAC13	Dynamic Contribution for PLL	VCC	1.5 V	2.60			µW/MHz
PAC15	Contribution of NVM block during a read operation (F < 33MHz)	VCC	1.5 V	358.00			µW/MHz
PAC16	1st contribution of NVM block during a read operation (F > 33MHz)	VCC	1.5 V	12.88			mW
PAC17	2nd contribution of NVM block during a read operation (F > 33MHz)	VCC	1.5 V	4.80			µW/MHz
PAC18	Main Crystal Oscillator contribution	VCCMAINXTAL	3.3 V	1.98			mW
PAC19a	RC Oscillator contribution	VCCRCOSC	3.3 V	3.30			mW
PAC19b	RC Oscillator contribution	VCC	1.5 V	3.00			mW
PAC20a	Analog Block Dynamic Power Contribution of the ADC	VCC33ADCx	3.3 V	8.25			mW
PAC20b	Analog Block Dynamic Power Contribution of the ADC	VCC15ADCx	1.5 V	3.00			mW
PAC21	Low Power Crystal Oscillator contribution	VCCLPXTAL	3.3 V	33.00			µW
PAC22	MSS Dynamic Power Contribution – Running Drysthone at 100MHz[1]	VCC	1.5 V	67.50			mW
PAC23	Temperature Monitor Power Contribution	See Table 2-94 on page 2-79	–	1.23			mW

P_{PLL} = 0 W

Embedded Nonvolatile Memory Dynamic Contribution—P_{eNVM}

SoC Mode

The eNVM dynamic power consumption is a piecewise linear function of frequency.

$P_{eNVM} = N_{eNVM\text{-}BLOCKS} * \beta_4 * P_{AC15} * F_{READ\text{-}eNVM}$ when $F_{READ\text{-}eNVM} \leq 33$ MHz,

$P_{eNVM} = N_{eNVM\text{-}BLOCKS} * \beta_4 * (P_{AC16} + P_{AC17} * F_{READ\text{-}eNVM})$ when $F_{READ\text{-}eNVM} > 33$ MHz

Where:

$N_{eNVM\text{-}BLOCKS}$ is the number of eNVM blocks used in the design.

β_4 is the eNVM enable rate for read operations. Default is 0 (eNVM mainly in idle state).

$F_{READ\text{-}eNVM}$ is the eNVM read clock frequency.

Standby Mode and Time Keeping Mode

P_{eNVM} = 0 W

Main Crystal Oscillator Dynamic Contribution—$P_{XTL\text{-}OSC}$

SoC Mode

$P_{XTL\text{-}OSC} = P_{AC18}$

Standby Mode

$P_{XTL\text{-}OSC}$ = 0 W

Time Keeping Mode

$P_{XTL\text{-}OSC}$ = 0 W

Low Power Oscillator Crystal Dynamic Contribution—$P_{LPXTAL\text{-}OSC}$

Operating, Standby, and Time Keeping Mode

$P_{LPXTAL\text{-}OSC} = P_{AC21}$

RC Oscillator Dynamic Contribution—$P_{RC\text{-}OSC}$

SoC Mode

$P_{RC\text{-}OSC} = P_{AC19A} + P_{AC19B}$

Standby Mode and Time Keeping Mode

$P_{RC\text{-}OSC}$ = 0 W

Analog System Dynamic Contribution—P_{AB}

SoC Mode

$P_{AB} = P_{AC23} * N_{TM} + P_{AC24} * N_{CM} + P_{AC25} * N_{ABPS} + P_{AC26} * N_{SDD} + P_{AC27} * N_{COMP} + P_{ADC} * N_{ADC} + P_{VR}$

Where:

N_{CM} is the number of current monitor blocks

N_{TM} is the number of temperature monitor blocks

N_{SDD} is the number of sigma-delta DAC blocks

N_{ABPS} is the number of ABPS blocks

N_{ADC} is the number of ADC blocks

N_{COMP} is the number of comparator blocks

$P_{VR} = P_{AC28}$

$P_{ADC} = P_{AC20A} + P_{AC20B}$

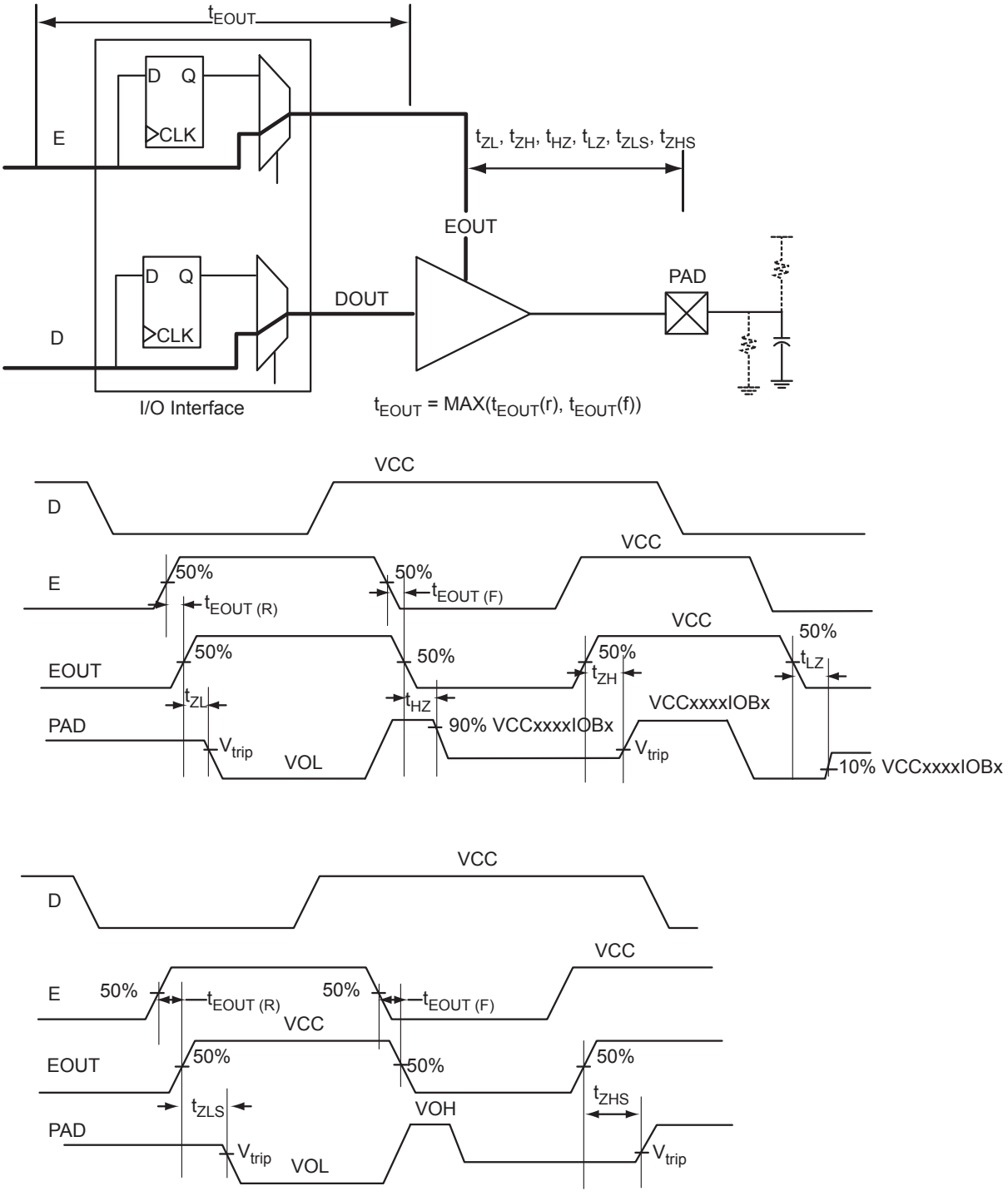


Figure 2-5 • **Tristate Output Buffer Timing Model and Delays (example)**

Table 2-28 • I/O Output Buffer Maximum Resistances[1]
Applicable to MSS I/O Banks

Standard	Drive Strength	$R_{PULL\text{-}DOWN}$ (Ω)[2]	$R_{PULL\text{-}UP}$ (Ω)[3]
3.3 V LVTTL / 3.3 V LVCMOS	8mA	50	150
2.5 V LVCMOS	8 mA	50	100
1.8 V LVCMOS	4 mA	100	112
1.5 V LVCMOS	2 mA	200	224

Notes:

1. *These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on VCCxxxxIOBx, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website.*
2. $R_{(PULL\text{-}DOWN\text{-}MAX)} = (V_{OLspec}) / I_{OLspec}$
3. $R_{(PULL\text{-}UP\text{-}MAX)} = (V_{CCImax} – V_{OHspec}) / I_{OHspec}$

Table 2-29 • I/O Weak Pull-Up/Pull-Down Resistances
Minimum and Maximum Weak Pull-Up/Pull-Down Resistance Values

VCCxxxxIOBx	$R_{(WEAK\ PULL\text{-}UP)}$[1] ($\Omega$)		$R_{(WEAK\ PULL\text{-}DOWN)}$[2] ($\Omega$)	
	Min.	Max.	Min.	Max.
3.3 V	10 k	45 k	10 k	45 k
2.5 V	11 k	55 k	12 k	74 k
1.8 V	18 k	70 k	17 k	110 k
1.5 V	19 k	90 k	19 k	140 k

Notes:

1. $R_{(WEAK\ PULL\text{-}UP\text{-}MAX)} = (VCCImax – VOHspec) / I_{(WEAK\ PULL\text{-}UP\text{-}MIN)}$
2. $R_{(WEAK\ PULL\text{-}DOWN\text{-}MAX)} = (VOLspec) / I_{(WEAK\ PULL\text{-}DOWN\text{-}MIN)}$

Single-Ended I/O Characteristics

3.3 V LVTTL / 3.3 V LVCMOS

Low-Voltage Transistor–Transistor Logic (LVTTL) is a general-purpose standard (EIA/JESD) for 3.3 V applications. It uses an LVTTL input buffer and push-pull output buffer.

Table 2-35 • Minimum and Maximum DC Input and Output Levels Applicable to FPGA I/O Banks

3.3 V LVTTL / 3.3 V LVCMOS	VIL		VIH		VOL	VOH	I_{OL}	I_{OH}	I_{OSL}	I_{OSH}	I_{IL}	I_{IH}
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA[1]	Max. mA[1]	µA[2]	µA[2]
2 mA	–0.3	0.8	2	3.6	0.4	2.4	2	2	27	25	15	15
4 mA	–0.3	0.8	2	3.6	0.4	2.4	4	4	27	25	15	15
6 mA	–0.3	0.8	2	3.6	0.4	2.4	6	6	54	51	15	15
8 mA	–0.3	0.8	2	3.6	0.4	2.4	8	8	54	51	15	15
12 mA	–0.3	0.8	2	3.6	0.4	2.4	12	12	109	103	15	15
16 mA	–0.3	0.8	2	3.6	0.4	2.4	16	16	127	132	15	15
24 mA	–0.3	0.8	2	3.6	0.4	2.4	24	24	181	268	10	10

Notes:

1. *Currents are measured at 100°C junction temperature and maximum voltage.*
2. *Currents are measured at 85°C junction temperature.*
3. *Software default selection highlighted in gray.*

Table 2-36 • Minimum and Maximum DC Input and Output Levels Applicable to MSS I/O Banks

3.3 V LVTTL / 3.3 V LVCMOS	VIL		VIH		VOL	VOH	I_{OL}	I_{OH}	I_{OSL}	I_{OSH}	I_{IL}	I_{IH}
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA[1]	Max. mA[1]	µA[2]	µA[2]
8 mA	–0.3	0.8	2	3.6	0.4	2.4	8	8	54	51	15	15

Notes:

1. *Currents are measured at 100°C junction temperature and maximum voltage.*
2. *Currents are measured at 85°C junction temperature.*
3. *Software default selection highlighted in gray.*

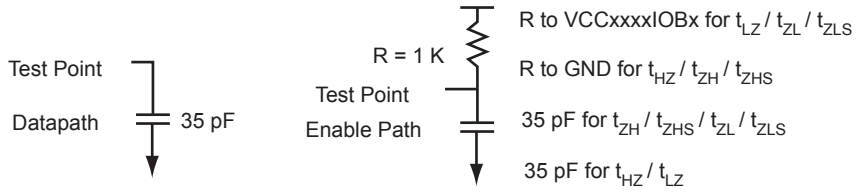


Figure 2-6 • AC Loading

Table 2-37 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V_{REF} (typ.) (V)	C_{LOAD} (pF)
0	3.3	1.4	–	35

*Note: *Measuring point = V_{trip}. See Table 2-22 on page 2-24 for a complete table of trip points.*

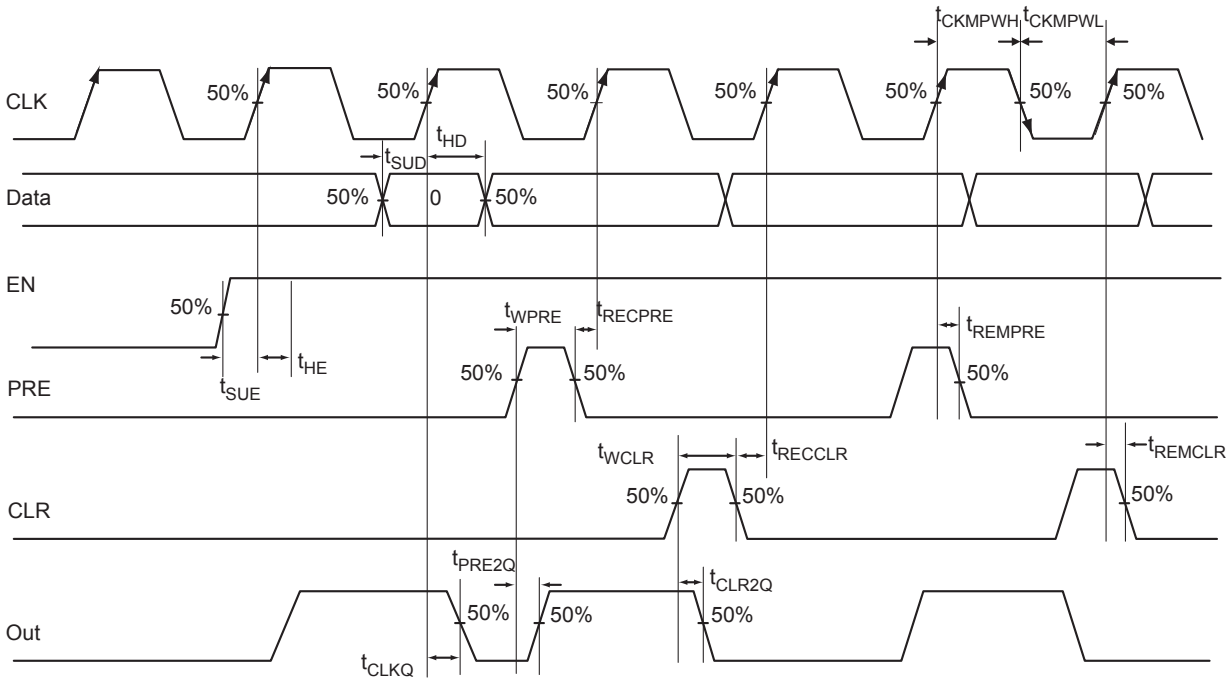


Figure 2-26 • **Timing Model and Waveforms**

Timing Characteristics

Table 2-79 • **Register Delays**
Worst Commercial-Case Conditions: T_J = 85°C, Worst-Case VCC = 1.425 V

Parameter	Description	–1	Std.	Units
t_{CLKQ}	Clock-to-Q of the Core Register	0.56	0.67	ns
t_{SUD}	Data Setup Time for the Core Register	0.44	0.52	ns
t_{HD}	Data Hold Time for the Core Register	0.00	0.00	ns
t_{SUE}	Enable Setup Time for the Core Register	0.46	0.55	ns
t_{HE}	Enable Hold Time for the Core Register	0.00	0.00	ns
t_{CLR2Q}	Asynchronous Clear-to-Q of the Core Register	0.41	0.49	ns
t_{PRE2Q}	Asynchronous Preset-to-Q of the Core Register	0.41	0.49	ns
t_{REMCLR}	Asynchronous Clear Removal Time for the Core Register	0.00	0.00	ns
t_{RECCLR}	Asynchronous Clear Recovery Time for the Core Register	0.23	0.27	ns
t_{REMPRE}	Asynchronous Preset Removal Time for the Core Register	0.00	0.00	ns
t_{RECPRE}	Asynchronous Preset Recovery Time for the Core Register	0.23	0.27	ns
t_{WCLR}	Asynchronous Clear Minimum Pulse Width for the Core Register	0.22	0.22	ns
t_{WPRE}	Asynchronous Preset Minimum Pulse Width for the Core Register	0.22	0.22	ns
t_{CKMPWH}	Clock Minimum Pulse Width High for the Core Register	0.32	0.32	ns
t_{CKMPWL}	Clock Minimum Pulse Width Low for the Core Register	0.36	0.36	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-9 for derating values.

Table 2-88 • RAM512X18
Worst Commercial-Case Conditions: T_J = 85°C, Worst-Case VCC = 1.425 V

Parameter	Description	–1	Std.	Units
t_{AS}	Address setup time	0.25	0.30	ns
t_{AH}	Address hold time	0.00	0.00	ns
t_{ENS}	REN, WEN setup time	0.09	0.11	ns
t_{ENH}	REN, WEN hold time	0.06	0.07	ns
t_{DS}	Input data (WD) setup time	0.19	0.22	ns
t_{DH}	Input data (WD) hold time	0.00	0.00	ns
t_{CKQ1}	Clock High to new data valid on RD (output retained, WMODE = 0)	2.19	2.63	ns
t_{CKQ2}	Clock High to new data valid on RD (pipelined)	0.91	1.09	ns
t_{C2CRWH} [1]	Address collision clk-to-clk delay for reliable read access after write on same address—applicable to opening edge	0.38	0.43	ns
t_{C2CWRH} [1]	Address collision clk-to-clk delay for reliable write access after read on same address—applicable to opening edge	0.44	0.50	ns
t_{RSTBQ}	RESET Low to data out Low on RD (flow-through)	0.94	1.12	ns
	RESET Low to data out Low on RD (pipelined)	0.94	1.12	ns
$t_{REMRSTB}$	RESET removal	0.29	0.35	ns
$t_{RECRSTB}$	RESET recovery	1.52	1.83	ns
$t_{MPWRSTB}$	RESET minimum pulse width	0.22	0.22	ns
t_{CYC}	Clock cycle time	3.28	3.28	ns
F_{MAX}	Maximum clock frequency	305	305	MHz

Notes:

1. *For more information, refer to the Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs application note.*
2. *For the derating values at specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-9 for derating values.*

Timing Characteristics

Table 2-89 • FIFO
Worst Commercial-Case Conditions: T_J = 85°C, VCC = 1.425 V

Parameter	Description	–1	Std.	Units
t_{ENS}	REN, WEN Setup Time	1.40	1.68	ns
t_{ENH}	REN, WEN Hold Time	0.02	0.02	ns
t_{BKS}	BLK Setup Time	0.19	0.19	ns
t_{BKH}	BLK Hold Time	0.00	0.00	ns
t_{DS}	Input Data (WD) Setup Time	0.19	0.22	ns
t_{DH}	Input Data (WD) Hold Time	0.00	0.00	ns
t_{CKQ1}	Clock High to New Data Valid on RD (flow-through)	2.39	2.87	ns
t_{CKQ2}	Clock High to New Data Valid on RD (pipelined)	0.91	1.09	ns
t_{RCKEF}	RCLK High to Empty Flag Valid	1.74	2.09	ns
t_{WCKFF}	WCLK High to Full Flag Valid	1.66	1.99	ns
t_{CKAF}	Clock HIGH to Almost Empty/Full Flag Valid	6.29	7.54	ns
t_{RSTFG}	RESET Low to Empty/Full Flag Valid	1.72	2.06	ns
t_{RSTAF}	RESET Low to Almost Empty/Full Flag Valid	6.22	7.47	ns
t_{RSTBQ}	RESET Low to Data Out Low on RD (flow-through)	0.94	1.12	ns
	RESET Low to Data Out Low on RD (pipelined)	0.94	1.12	ns
$t_{REMRSTB}$	RESET Removal	0.29	0.35	ns
$t_{RECRSTB}$	RESET Recovery	1.52	1.83	ns
$t_{MPWRSTB}$	RESET Minimum Pulse Width	0.22	0.22	ns
t_{CYC}	Clock Cycle Time	3.28	3.28	ns
F_{MAX}	Maximum Frequency for FIFO	305	305	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-9 for derating values.

Programmable Analog Specifications

Current Monitor

Unless otherwise noted, current monitor performance is specified at 25°C with nominal power supply voltages, with the output measured using the internal voltage reference with the internal ADC in 12-bit mode and 91 Ksps, after digital compensation. All results are based on averaging over 16 samples.

***Table 2-93* • Current Monitor Performance Specification**

Specification	Test Conditions	Min.	Typical	Max.	Units
Input voltage range (for driving ADC over full range)		0 – 48	0 – 50	1 – 51	mV
Analog gain	From the differential voltage across the input pads to the ADC input		50		V/V
Input referred offset voltage	Input referred offset voltage	0	0.1	0.5	mV
	–40ºC to +100ºC	0	0.1	0.5	mV
Gain error	Slope of BFSL vs. 50 V/V		±0.1	±0.5	% nom.
	–40ºC to +100ºC			±0.5	% nom.
Overall Accuracy	Peak error from ideal transfer function, 25°C		±(0.1 + 0.25%)	±(0.4 + 1.5%)	mV plus % reading
Input referred noise	0 VDC input (no output averaging)	0.3	0.4	0.5	mVrms
Common-mode rejection ratio	0 V to 12 VDC common-mode voltage	–86	–87		dB
Analog settling time	To 0.1% of final value (with ADC load)				
	From CM_STB (High)	5			µs
	From ADC_START (High)	5		200	µs
Input capacitance			8		pF
Input biased current	CM[n] or TM[n] pad, –40°C to +100°C over maximum input voltage range (plus is into pad)				
	Strobe = 0; IBIAS on CM[n]		0		µA
	Strobe = 1; IBIAS on CM[n]		1		µA
	Strobe = 0; IBIAS on TM[n]		2		µA
	Strobe = 1; IBIAS on TM[n]		1		µA
Power supply rejection ratio	DC (0 – 10 KHz)	41	42		dB
Incremental operational current monitor power supply current requirements (per current monitor instance, not including ADC or VAREFx)	VCC33A		150		µA
	VCC33AP		140		µA
	VCC15A		50		µA

Note: Under no condition should the TM pad ever be greater than 10 mV above the CM pad. This restriction is applicable only if current monitor is used.

Serial Peripheral Interface (SPI) Characteristics

This section describes the DC and switching of the SPI interface. Unless otherwise noted, all output characteristics given for a 35 pF load on the pins and all sequential timing characteristics are related to SPI_x_CLK. For timing parameter definitions, refer to Figure 2-47 on page 2-90.

***Table 2-100* • SPI Characteristics**
Commercial Case Conditions: T_J = 85ºC, VDD = 1.425 V, –1 Speed Grade

Symbol	Description and Condition	A2F060	A2F200	A2F500	Unit
sp1	SPI_x_CLK minimum period				
	SPI_x_CLK = PCLK/2	20	NA	20	ns
	SPI_x_CLK = PCLK/4	40	40	40	ns
	SPI_x_CLK = PCLK/8	80	80	80	ns
	SPI_x_CLK = PCLK/16	0.16	0.16	0.16	µs
	SPI_x_CLK = PCLK/32	0.32	0.32	0.32	µs
	SPI_x_CLK = PCLK/64	0.64	0.64	0.64	µs
	SPI_x_CLK = PCLK/128	1.28	1.28	1.28	µs
	SPI_x_CLK = PCLK/256	2.56	2.56	2.56	µs
sp2	SPI_x_CLK minimum pulse width high				
	SPI_x_CLK = PCLK/2	10	NA	10	ns
	SPI_x_CLK = PCLK/4	20	20	20	ns
	SPI_x_CLK = PCLK/8	40	40	40	ns
	SPI_x_CLK = PCLK/16	0.08	0.08	0.08	µs
	SPI_x_CLK = PCLK/32	0.16	0.16	0.16	µs
	SPI_x_CLK = PCLK/64	0.32	0.32	0.32	µs
	SPI_x_CLK = PCLK/128	0.64	0.64	0.64	µs
	SPI_x_CLK = PCLK/256	1.28	1.28	1.28	us
sp3	SPI_x_CLK minimum pulse width low				
	SPI_x_CLK = PCLK/2	10	NA	10	ns
	SPI_x_CLK = PCLK/4	20	20	20	ns
	SPI_x_CLK = PCLK/8	40	40	40	ns
	SPI_x_CLK = PCLK/16	0.08	0.08	0.08	µs
	SPI_x_CLK = PCLK/32	0.16	0.16	0.16	µs
	SPI_x_CLK = PCLK/64	0.32	0.32	0.32	µs
	SPI_x_CLK = PCLK/128	0.64	0.64	0.64	µs
	SPI_x_CLK = PCLK/256	1.28	1.28	1.28	µs
sp4	SPI_x_CLK, SPI_x_DO, SPI_x_SS rise time (10%-90%) [1]	4.7	4.7	4.7	ns
sp5	SPI_x_CLK, SPI_x_DO, SPI_x_SS fall time (10%-90%) [1]	3.4	3.4	3.4	ns

Notes:

1. *These values are provided for a load of 35 pF. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website: http://www.microsemi.com/index.php?option=com_microsemi&Itemid=489&lang=en&view=salescontact.*
2. *For allowable pclk configurations, refer to the Serial Peripheral Interface Controller section in the SmartFusion Microcontroller Subsystem User's Guide.*

3 – SmartFusion Development Tools

Designing with SmartFusion cSoCs involves three different types of design: FPGA design, embedded design and analog design. These roles can be filled by three different designers, two designers or even a single designer, depending on company structure and project complexity.

Types of Design Tools

Microsemi has developed design tools and flows to meet the needs of these three types of designers so they can work together smoothly on a single project (Figure 3-1).

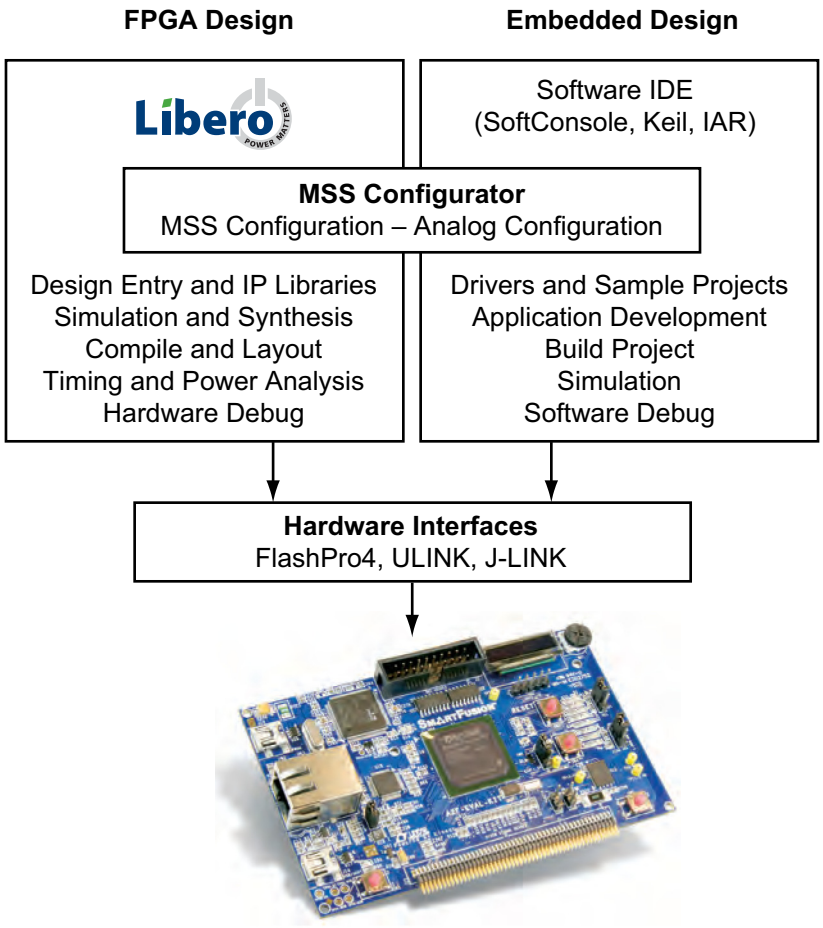


Figure 3-1 • **Three Design Roles**

FPGA Design

Libero System-on-Chip (SoC) software is Microsemi's comprehensive software toolset for designing with all Microsemi FPGAs and cSoCs. Libero SoC includes industry-leading synthesis, simulation and debug tools from Synopsys® and Mentor Graphics®, as well as innovative timing and power optimization and analysis.

Analog Front-End Pin-Level Function Multiplexing

Table 5-2 describes the relationships between the various internal signals found in the analog front-end (AFE) and how they are multiplexed onto the external package pins. Note that, in general, only one function is available for those pads that have numerous functions listed. The exclusion to this rule is when a comparator is used; the ADC can still convert either input side of the comparator.

***Table 5-2* • Relationships Between Signals in the Analog Front-End**

Pin	ADC Channel	Dir.-In Option	Prescaler	Current Mon.	Temp. Mon.	Compar.	LVTTL	SDD MUX	SDD
ABPS0	ADC0_CH1		ABPS0_IN						
ABPS1	ADC0_CH2		ABPS1_IN						
ABPS2	ADC0_CH5		ABPS2_IN						
ABPS3	ADC0_CH6		ABPS3_IN						
ABPS4	ADC1_CH1		ABPS4_IN						
ABPS5	ADC1_CH2		ABPS5_IN						
ABPS6	ADC1_CH5		ABPS6_IN						
ABPS7	ADC1_CH6		ABPS7_IN						
ABPS8	ADC2_CH1		ABPS8_IN						
ABPS9	ADC2_CH2		ABPS9_IN						
ADC0	ADC0_CH9	Yes				CMP1_P	LVTTL0_IN		
ADC1	ADC0_CH10	Yes				CMP1_N	LVTTL1_IN	SDDM0_OUT	
ADC2	ADC0_CH11	Yes				CMP3_P	LVTTL2_IN		
ADC3	ADC0_CH12	Yes				CMP3_N	LVTTL3_IN	SDDM1_OUT	
ADC4	ADC1_CH9	Yes				CMP5_P	LVTTL4_IN		
ADC5	ADC1_CH10	Yes				CMP5_N	LVTTL5_IN	SDDM2_OUT	
ADC6	ADC1_CH11	Yes				CMP7_P	LVTTL6_IN		
ADC7	ADC1_CH12	Yes				CMP7_N	LVTTL7_IN	SDDM3_OUT	
ADC8	ADC2_CH9	Yes				CMP9_P	LVTTL8_IN		
ADC9	ADC2_CH10	Yes				CMP9_N	LVTTL9_IN	SDDM4_OUT	
ADC10	ADC2_CH11	Yes					LVTTL10_IN		
ADC11	ADC2_CH12	Yes					LVTTL11_IN		
CM0	ADC0_CH3	Yes		CM0_H		CMP0_P			
CM1	ADC0_CH7	Yes		CM1_H		CMP2_P			
CM2	ADC1_CH3	Yes		CM2_H		CMP4_P			
CM3	ADC1_CH7	Yes		CM3_H		CMP6_P			
CM4	ADC2_CH3	Yes		CM4_H		CMP8_P			
SDD0	ADC0_CH15								SDD0_OUT
SDD1	ADC1_CH15								SDD1_OUT

Notes:

1. *ABPSx_IN: Input to active bipolar prescaler channel x.*
2. *CMx_H/L: Current monitor channel x, high/low side.*
3. *TMx_IO: Temperature monitor channel x.*
4. *CMPx_P/N: Comparator channel x, positive/negative input.*
5. *LVTTLx_IN: LVTTL I/O channel x.*
6. *SDDMx_OUT: Output from sigma-delta DAC MUX channel x.*
7. *SDDx_OUT: Direct output from sigma-delta DAC channel x.*

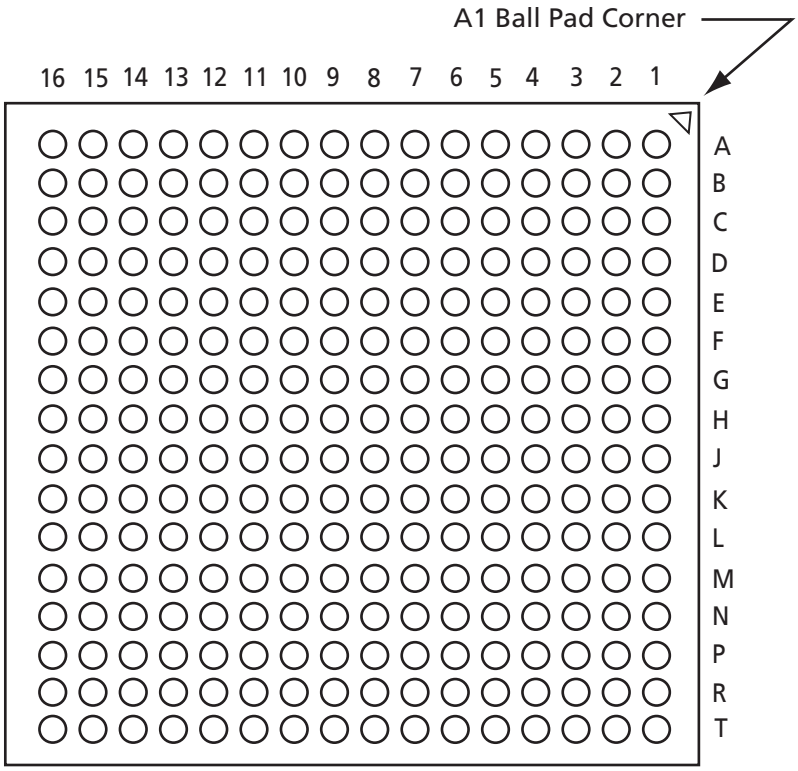
***Table 5-2* • Relationships Between Signals in the Analog Front-End**

Pin	ADC Channel	Dir.-In Option	Prescaler	Current Mon.	Temp. Mon.	Compar.	LVTTL	SDD MUX	SDD
SDD2	ADC2_CH15								SDD2_OUT
TM0	ADC0_CH4	Yes		CM0_L	TM0_IO	CMP0_N			
TM1	ADC0_CH8	Yes		CM1_L	TM1_IO	CMP2_N			
TM2	ADC1_CH4	Yes		CM2_L	TM2_IO	CMP4_N			
TM3	ADC1_CH8	Yes		CM3_L	TM3_IO	CMP6_N			
TM4	ADC2_CH4	Yes		CM4_L	TM4_IO	CMP8_N			

Notes:

1. *ABPSx_IN: Input to active bipolar prescaler channel x.*
2. *CMx_H/L: Current monitor channel x, high/low side.*
3. *TMx_IO: Temperature monitor channel x.*
4. *CMPx_P/N: Comparator channel x, positive/negative input.*
5. *LVTTLx_IN: LVTTL I/O channel x.*
6. *SDDMx_OUT: Output from sigma-delta DAC MUX channel x.*
7. *SDDx_OUT: Direct output from sigma-delta DAC channel x.*

FG256



Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/soc/products/solutions/package/docs.aspx.

Pin Number	FG484	
	A2F200 Function	A2F500 Function
M21	VPP	VPP
M22	IO32NDB1V0	IO41NDB1V0
N1	GND	GND
N2	NC	IO70PDB5V0
N3	NC	IO70NDB5V0
N4	VCCRCOSC	VCCRCOSC
N5	VCCFPGAIOB5	VCCFPGAIOB5
N6	NC	IO68NDB5V0
N7	VCCFPGAIOB5	VCCFPGAIOB5
N8	GND	GND
N9	VCC	VCC
N10	GND	GND
N11	VCC	VCC
N12	GND	GND
N13	VCC	VCC
N14	GND	GND
N15	VCC	VCC
N16	NC	GND
N17	NC	NC
N18	VCCFPGAIOB1	VCCFPGAIOB1
N19	VCCENVM	VCCENVM
N20	GNDENVM	GNDENVM
N21	NC	NC
N22	GND	GND
P1	NC	IO69NDB5V0
P2	NC	IO69PDB5V0
P3	GNDRCOSC	GNDRCOSC
P4	GND	GND
P5	NC	NC
P6	NC	NC
P7	GND	GND
P8	VCC	VCC
P9	GND	GND
P10	VCC	VCC

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Revision	Changes	Page
Revision 9 (continued)	The following note was added to Table 2-86 • SmartFusion CCC/PLL Specification in regard to delay increments in programmable delay blocks (SAR 34816): "When the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available. Refer to SmartGen online help for more information."	2-63
	Figure 2-36 • FIFO Read and Figure 2-37 • FIFO Write have been added (SAR 34851).	2-72
	Information regarding the MSS resetting itself after IAP of the FPGA fabric was added to the "Reprogramming the FPGA Fabric Using the Cortex-M3" section (SAR 37970).	4-8
	Instructions for unused VCC33ADCx pins were revised in "Supply Pins" (SAR 41137).	5-1
	Libero IDE was changed to Libero SoC throughout the document (SAR 40264).	N/A
Revision 8 (March 2012)	In the "Analog Front-End (AFE)" section, the resolution for the first-order sigma delta DAC was corrected from 12-bit to "8-bit, 16-bit, or 24-bit." The same correction was made in the "SmartFusion cSoC Family Product Table" (SAR 36541).	I, II
	The "SmartFusion cSoC Family Product Table" was revised to break out the features by package as well as device. The table now indicates that only one SPI is available for the PQ208 package in A2F200 and A2F500, and in the TQ144 package for A2F060 (SAR 33477). The EMC address bus size has been corrected to 26 bits (SAR 35664).	II
	The "SmartFusion cSoC Device Status" table was revised to change the CS288 package for A2F200 and A2F500 from preliminary to production status (SAR 37811).	III
	TQ144 package information for A2F060 was added to the "Package I/Os: MSS + FPGA I/Os" table, "SmartFusion cSoC Device Status" table, "Product Ordering Codes", and "Temperature Grade Offerings" table (SAR 36246).	III, VI
	Table 1 • SmartFusion cSoC Package Sizes Dimensions is new (SAR 31178).	III
	The Halogen-Free Packaging code (H) was removed from the "Product Ordering Codes" table (SAR 34017).	VI
	The "Specifying I/O States During Programming" section is new (SAR 34836).	1-3
	The reference to guidelines for global spines and VersaTile rows, given in the "Global Clock Dynamic Contribution—P_{CLOCK}" section, was corrected to the "Device Architecture" chapter in the *SmartFusion FPGA Fabric User's Guide* (SAR 34742).	2-15
	The AC Loading figures in the "Single-Ended I/O Characteristics" section were updated to match tables in the "Summary of I/O Timing Characteristics – Default I/O Software Settings" section (SAR 34891).	2-30, 2-24
	The following sentence was deleted from the "2.5 V LVCMOS" section (SAR 34799): "It uses a 5 V–tolerant input buffer and push-pull output buffer."	2-32
	In the SRAM "Timing Characteristics" tables, reference was made to a new application note, *Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs*, which covers these cases in detail (SAR 34874).	2-69
	The note for Table 2-93 • Current Monitor Performance Specification was modified to include the statement that the restriction on the TM pad being no greater than 10 mV above the CM pad.is applicable only if current monitor is used (SAR 26373).	2-78
	The unit "FR" in Table 2-96 • ABPS Performance Specifications and Table 2-98 • Analog Sigma-Delta DAC, used to designate full-scale error, was changed to "FS" and clarified with a table note (SAR 35342).	2-82, 2-85

Revision	Changes	Page
Revision 6 (continued)	Dynamic power values were updated in the following tables. The table subtitles changed where FPGA I/O banks were involved to note "I/O assigned to EMC I/O pins" (SAR 30987). Table 2-10 • Summary of I/O Input Buffer Power (per pin) – Default I/O Software Settings Table 2-13 • Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings.	2-10 2-11
	The "Timing Model" was updated (SAR 30986).	2-19
	Values in the timing tables for the following sections were updated. Table subtitles were updated for FPGA I/O banks to note "I/O assigned to EMC I/O pins" (SAR 30986). "Overview of I/O Performance" section: Table 2-24, Table 2-25 "Detailed I/O DC Characteristics" section: Table 2-38, Table 2-39, Table 2-40, Table 2-44, Table 2-45, Table 2-46, Table 2-50, Table 2-51, Table 2-52, Table 2-56, Table 2-57, Table 2-58, Table 2-61, Table 2-62 "LVDS" section: Table 2-65 "LVPECL" section: Table 2-68 "Global Tree Timing Characteristics" section: Table 2-80, Table 2-81	2-23 2-26 2-40 2-42 2-59
	The "PQ208" section and pin tables are new (SAR 31005).	5-34
	Global clocks were removed from the A2F060 pin table for the "CS288" and "FG256" packages, resulting in changed function names for affected pins (SAR 31033).	5-43
Revision 5 (December 2010)	Table 2-2 • Analog Maximum Ratings was revised. The recommended CM[n] pad voltage (relative to ground) was changed from –11 to –0.3 (SAR 28219).	2-2
	Table 2-7 • Temperature and Voltage Derating Factors for Timing Delays was revised to change the values for 100ºC.	2-9
	Power-down and Sleep modes, and all associated notes, were removed from Table 2-8 • Power Supplies Configuration (SAR 29479). IDC3 and IDC4 were renamed to IDC1 and IDC2 (SAR 29478). These modes are no longer supported. A note was added to the table stating that current monitors and temperature monitors should not be used when Power-down and/or Sleep mode are required by the application.	2-10
	The "Power-Down and Sleep Mode Implementation" section was deleted (SAR 29479).	N/A
	Values for PAC9 and PAC10 for LVDS and LVPECL were revised in Table 2-10 • Summary of I/O Input Buffer Power (per pin) – Default I/O Software Settings and Table 2-12 • Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings*.	2-10, 2-11
	Values for PAC1 through PAC4, PDC1, and PDC2 were added for A2F500 in Table 2-14 • Different Components Contributing to Dynamic Power Consumption in SmartFusion cSoCs and Table 2-15 • Different Components Contributing to the Static Power Consumption in SmartFusion cSoCs	2-12, 2-13
	The equation for "Total Dynamic Power Consumption—P_{DYN}" in "SoC Mode" was revised to add P_{MSS}. The "Microcontroller Subsystem Dynamic Contribution—P_{MSS}" section is new (SAR 29462).	2-14, 2-18
	Information in Table 2-24 • Summary of I/O Timing Characteristics—Software Default Settings (applicable to FPGA I/O banks) and Table 2-25 • Summary of I/O Timing Characteristics—Software Default Settings (applicable to MSS I/O banks) was updated.	2-25

Revision	Changes	Page
Revision 5 (continued)	Available values for the Std. speed were added to the timing tables from Table 2-38 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew to Table 2-92 • JTAG 1532 (SAR 29331). One or more values changed for the –1 speed in tables covering 3.3 V LVCMOS, 2.5 V LVCMOS, 1.8 V LVCMOS, 1.5 V LVCMOS, Combinatorial Cell Propagation Delays, and A2F200 Global Resources.	2-31 to 2-76
	Table 2-80 • A2F500 Global Resource is new.	2-60
	Table 2-90 • eNVM Block Timing, Worst Commercial Case Conditions: T_J = 85°C, VCC = 1.425 V was revised (SAR 27585).	2-76
	The programmable analog specifications tables were revised with updated information.	2-78 to 2-87
	Table 4-1 • Supported JTAG Programming Hardware was revised by adding a note to indicate "planned support" for several of the items in the table.	4-7
	The note on JTAGSEL in the "In-System Programming" section was revised to state that SoftConsole selects the appropriate TAP controller using the CTXSELECT JTAG command. When using SoftConsole, the state of JTAGSEL is a "don't care" (SAR 29261).	4-7
	The "CS288" and "FG256" pin tables for A2F060 are new, comparing the A2F060 function with the A2F200 function (SAR 29353).	5-24
	The "Handling When Unused" column was removed from the "FG256" pin table for A2F200 and A2F500 (SAR 29691).	5-42
Revision 4 (September 2010)	Table 2-8 • Power Supplies Configuration was revised. VCCRCOSC was moved to a column of its own with new values. VCCENVM was added to the table. Standby mode for VJTAG and VPP was changed from 0 V to N/A. "Disable" was changed to "Off" in the eNVM column. The column for RCOSC was deleted.	2-10
	The "Power-Down and Sleep Mode Implementation" section was revised to include VCCROSC.	2-11
Revision 3 (September 2010)	The "I/Os and Operating Voltage" section was revised to list "single 3.3 V power supply with on-chip 1.5 V regulator" and "external 1.5 V is allowed" (SAR 27663).	I
	The CS288 package was added to the "Package I/Os: MSS + FPGA I/Os" table (SAR 27101), "Product Ordering Codes" table, and "Temperature Grade Offerings" table (SAR 27044). The number of direct analog inputs for the FG256 package in A2F060 was changed from 8 to 6.	III, VI, VI
	Two notes were added to the "SmartFusion cSoC Family Product Table" indicating limitations for features of the A2F500 device: *Two PLLs are available in CS288 and FG484 (one PLL in FG256).* *[ADCs, DACs, SCBs, comparators, current monitors, and bipolar high voltage monitors are] Available on FG484 only. FG256 and CS288 packages offer the same programmable analog capabilities as A2F200.* Table cells were merged in rows containing the same values for easier reading (SAR 24748).	II
	The security feature option was added to the "Product Ordering Codes" table.	VI